

Product Overview

The NSI826xC devices are high reliability six-channel digital isolators. The NSI826xC device is safety certified by UL1577 support several insulation withstand voltage(5kV), while providing high electromagnetic immunity and low emissions at low power consumption. The data rate of the NSI826xC is up to 150Mbps, and the common-mode transient immunity (CMTI) is up to 250kV/us. The NSI826xC device provides digital channel direction configuration and the default output level configuration when the input power is lost. Wide supply voltage of the NSI826xC device supports to connect with most digital interface directly, easy to do the level shift. High system level EMC performance enhance reliability and stability of use.

Key Features

- Up to 5000V_{rms} Insulation voltage
- Data rate: DC to 150Mbps
- Power supply voltage: 2.5V to 5.5V
- High CMTI: 250kV/us
- Chip level ESD: HBM: ±8kV
- High system level EMC performance:
 - Enhanced system level ESD, EFT, Surge immunity
- Default output high level or low level option
- Low power consumption: 1.5mA/ch (1 Mbps)
- Low propagation delay: <15ns
- Operation temperature: -40°C~125°C
- RoHS-compliant packages:
 - SOP16(300mil)

Safety Regulatory Approvals

- UL recognition: up to 5000V_{rms} for 1 minute per UL1577
- CQC certification per GB4943.1
- CSA component notice 5A
- DIN EN IEC 60747-17 (VDE 0884-17)

Applications

- Industrial automation system
- Isolated SPI, RS232, RS485
- General-purpose multichannel isolation

Device Information

| Part Number | Package | Body Size |
|----------------|---------------|------------------|
| NSI826xCx-DSWR | SOP16(300mil) | 10.30mm × 7.50mm |

Functional Block Diagrams

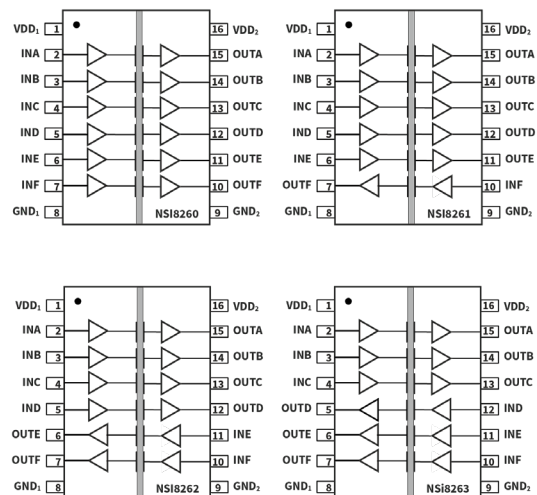


Figure 1. NSI826xC Block Diagram

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1. Pin Configuration and Functions

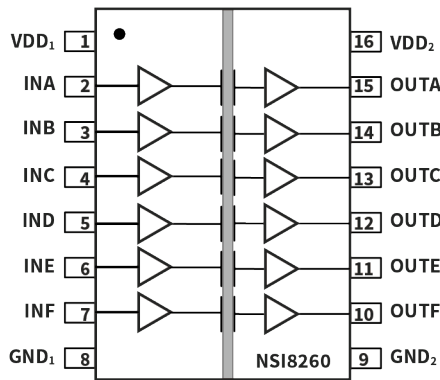


Figure 1.1 NSI8260 SOP16 Package

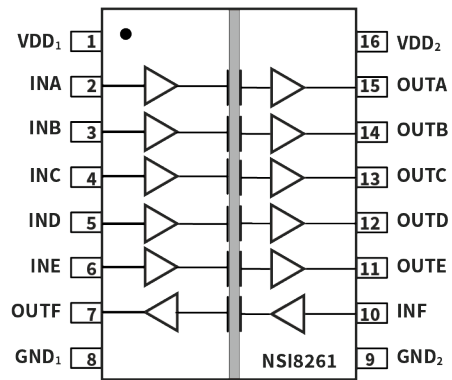


Figure 1.2 NSI8261 SOP16 Package

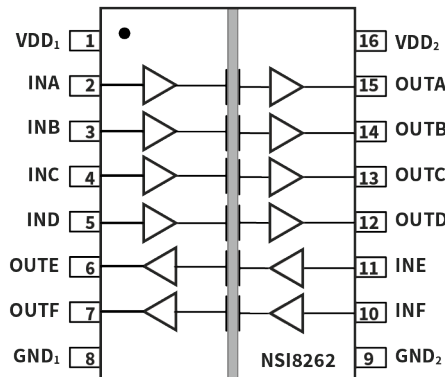


Figure 1.3 NSI8262 SOP16 Package

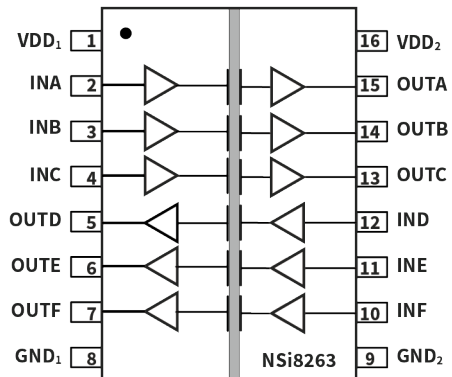


Figure 1.4 NSI8263 SOP16 Package

Table 1.1 NSI8260/ NSI8261/ NSI8262 SOP16 Pin Configuration and Description

| NSI8260 PIN NO. | NSI8261 PIN NO. | NSI8262 PIN NO. | NSI8263 PIN NO. | SYMBOL | FUNCTION |
|--------------------|--------------------|--------------------|--------------------|------------------|--|
| 1 | 1 | 1 | 1 | VDD ₁ | Power Supply for Isolator Side 1 |
| 2 | 2 | 2 | 2 | INA | Logic Input A |
| 3 | 3 | 3 | 3 | INB | Logic Input B |
| 4 | 4 | 4 | 4 | INC | Logic Input C |
| 5 | 5 | 5 | 12 | IND | Logic Input D |
| 6 | 6 | 11 | 11 | INE | Logic Input E |
| 7 | 10 | 10 | 10 | INF | Logic Input F |
| 8 | 8 | 8 | 8 | GND ₁ | Ground 1, the ground reference for Isolator Side 1 |
| 9 | 9 | 9 | 9 | GND ₂ | Ground 2, the ground reference for Isolator Side 2 |

| NSI8260 PIN NO. | NSI8261 PIN NO. | NSI8262 PIN NO. | NSI8263 PIN NO. | SYMBOL | FUNCTION |
|--------------------|--------------------|--------------------|--------------------|--------|----------------------------------|
| 10 | 7 | 7 | 7 | OUTF | Logic Output F |
| 11 | 11 | 6 | 6 | OUTE | Logic Output E |
| 12 | 12 | 12 | 5 | OUTD | Logic Output D |
| 13 | 13 | 13 | 13 | OUTC | Logic Output C |
| 14 | 14 | 14 | 14 | OUTB | Logic Output B |
| 15 | 15 | 15 | 15 | OUTA | Logic Output A |
| 16 | 16 | 16 | 16 | VDD2 | Power Supply for Isolator Side 2 |

2. Absolute Maximum Ratings

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|------------------------------------|---|------|-----|---------|------|---|
| Power Supply Voltage | VDD1, VDD2 | -0.5 | | 6.5 | V | |
| Maximum Input Voltage | VINA, VINB, VINC, VIND, VINE, VINI | -0.4 | | VDD+0.4 | V | |
| Maximum Output Voltage | VOUTA, VOUTB, VOUTC, VOUTD, VOUTE, VOUTF | -0.4 | | VDD+0.4 | V | |
| Maximum Input/Output Pulse Voltage | ALL I/O Pin | -0.8 | | VDD+0.8 | V | Pulse width should be less than 100ns, and the duty cycle should be less than 10% |
| Output current | I _o | -15 | | 15 | mA | |
| Operating Temperature | T _{opr} | -40 | | 125 | °C | |
| Junction Temperature | T _j | | | 150 | °C | |
| Storage Temperature | T _{stg} | -65 | | 150 | °C | |
| Electrostatic discharge | HBM | | | ±8000 | V | |
| | CDM | | | ±2000 | V | |

3. Recommended Operating Conditions

| <i>Parameters</i> | <i>Symbol</i> | <i>min</i> | <i>typ</i> | <i>max</i> | <i>unit</i> |
|--------------------------|------------------|------------|------------|------------|-------------|
| Power Supply Voltage | VDD1, VDD2 | 2.5 | | 5.5 | V |
| Operating Temperature | T _{opr} | -40 | | 125 | °C |
| High Level Input Voltage | VIH | 2 | | | V |
| Low Level Input Voltage | VIL | | | 0.8 | V |
| Data rate | DR | | | 150 | Mbps |

4. Thermal Characteristics

| <i>Parameters</i> | <i>Symbol</i> | <i>SOP16(300mil)</i> | <i>Unit</i> |
|---|---------------------|----------------------|-------------|
| IC Junction-to-Air Thermal Resistance | θ_{JA} | 60.3 | °C/W |
| Junction-to-case (top) thermal resistance | $\theta_{JC (top)}$ | 24.0 | °C/W |
| Junction-to-board thermal resistance | θ_{JB} | 29.3 | °C/W |

5. Specifications

5.1. Electrical Characteristics

(VDD1=2.5V~5.5V, VDD2=2.5V~5.5V, T_A=-40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 5V, VDD2 = 5V, T_A = 25°C)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|------------------------------------|---------------------|---------|------|-----|-------|---|
| Power on Reset | VDD _{POR} | 2 | 2.2 | 2.4 | V | POR threshold as during power-up |
| | VDD _{HYS} | | 0.1 | | V | POR threshold Hysteresis |
| Rising input switching threshold | V _{IT+} | | 1.6 | 2 | V | |
| Falling input switching threshold | V _{IT-} | 0.8 | 1.2 | | V | |
| Input threshold voltage hysteresis | V _{I(HYS)} | | 0.4 | | V | |
| High Level Output Voltage | V _{OH} | VDD-0.4 | | | V | I _{OH} =- 4mA |
| Low Level Output Voltage | V _{OL} | | | 0.4 | V | I _{OL} = 4mA |
| Output Impedance | R _{out} | | 50 | | ohm | |
| Input Pull high or low Current | I _{pull} | | 8 | 15 | µA | |
| Start Up Time after POR | t _{rs} | | 10 | | µs | |
| Common Mode Transient Immunity | CMTI | ±200 | ±250 | | kV/µs | See Figure 5.12 , C _L = 15pF |

5.2. Supply Current Characteristics – 5V Supply

(VDD1=5V± 10%, VDD2=5V± 10%, T_A=-40°C to 125°C. Unless otherwise noted, Typical values are at **VDD1 = 5V, VDD2 = 5V, T_A = 25°C**)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|----------------|-----------------------|-----|------|-------|------|---|
| Supply current | NSI8260 | | | | | |
| | I _{DD1} (Q0) | | 1.39 | 3.09 | mA | All Input 0V for NSI8260x0 Or All Input at supply for NSI8260x1 |
| | I _{DD2} (Q0) | | 3.41 | 5.63 | mA | |
| | I _{DD1} (Q1) | | 7.37 | 12.16 | mA | All Input at supply for NSI8260x0 Or All Input 0V for NSI8260x1 |
| | I _{DD2} (Q1) | | 3.49 | 5.76 | mA | |

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|----------------|-------------------------|-----|-------|-------|------|---|
| | I _{DD1} (1M) | | 4.39 | 7.24 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.67 | 6.06 | mA | |
| | I _{DD1} (10M) | | 4.71 | 7.77 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 5.66 | 9.34 | mA | |
| | I _{DD1} (100M) | | 7.47 | 14.94 | mA | All Input with 100Mbps, C _L =15pF |
| | I _{DD2} (100M) | | 23.8 | 55.22 | mA | |
| NSI8261 | | | | | | |
| | I _{DD1} (Q0) | | 1.73 | 2.85 | mA | All Input 0V for NSI8261x0 Or All Input at supply for NSI8261x1 |
| | I _{DD2} (Q0) | | 3.07 | 5.07 | mA | |
| | I _{DD1} (Q1) | | 6.72 | 11.09 | mA | All Input at supply for NSI8261x0 Or All Input 0V for NSI8261x1 |
| | I _{DD2} (Q1) | | 4.14 | 6.83 | mA | |
| | I _{DD1} (1M) | | 4.27 | 7.05 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.79 | 6.25 | mA | |
| | I _{DD1} (10M) | | 4.87 | 8.03 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 5.50 | 9.08 | mA | |
| | I _{DD1} (100M) | | 10.19 | 20.38 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 21.08 | 47.21 | mA | |
| NSI8262 | | | | | | |
| | I _{DD1} (Q0) | | 2.06 | 3.40 | mA | All Input 0V for NSI8262x0 Or All Input at supply for NSI8262x1 |
| | I _{DD2} (Q0) | | 2.74 | 4.52 | mA | |
| | I _{DD1} (Q1) | | 6.08 | 10.03 | mA | All Input at supply for NSI8262x0 Or All Input 0V for NSI8262x1 |
| | I _{DD2} (Q1) | | 4.78 | 7.89 | mA | |
| | I _{DD1} (1M) | | 4.15 | 6.85 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.91 | 6.45 | mA | |
| | I _{DD1} (10M) | | 5.03 | 8.29 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 5.34 | 8.82 | mA | |
| | I _{DD1} (100M) | | 12.91 | 25.83 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 18.36 | 39.2 | mA | |
| NSI8263 | | | | | | |

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|------------|-------------------------|-----|-------|-------|------|---|
| | I _{DD1} (Q0) | | 2.40 | 3.96 | mA | All Input 0V for NSI8263x0 Or All Input at supply for NSI8263x1 |
| | I _{DD2} (Q0) | | 2.40 | 3.96 | mA | |
| | I _{DD1} (Q1) | | 5.43 | 8.96 | mA | All Input at supply for NSI8263x0 Or All Input 0V for NSI8263x1 |
| | I _{DD2} (Q1) | | 5.43 | 8.96 | mA | |
| | I _{DD1} (1M) | | 4.03 | 6.65 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 4.03 | 6.65 | mA | |
| | I _{DD1} (10M) | | 5.19 | 8.56 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 5.19 | 8.56 | mA | |
| | I _{DD1} (100M) | | 15.64 | 31.27 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 15.64 | 31.27 | mA | |

5.3. Supply Current Characteristics –3.3V Supply

(VDD1=3.3V± 10%, VDD2=3.3V± 10%, T_A=-40°C to 125°C. Unless otherwise noted, Typical values are at **VDD1 = 3.3V, VDD2 = 3.3V, T_A = 25°C**)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|----------------|-------------------------|-----|-------|-------|------|---|
| Supply current | NSI8260 | | | | | |
| | I _{DD1} (Q0) | | 1.33 | 3.00 | mA | All Input 0V for NSI8260x0 Or All Input at supply for NSI8260x1 |
| | I _{DD2} (Q0) | | 3.36 | 5.54 | mA | |
| | I _{DD1} (Q1) | | 7.26 | 11.98 | mA | All Input at supply for NSI8260x0 Or All Input 0V for NSI8260x1 |
| | I _{DD2} (Q1) | | 3.43 | 5.66 | mA | |
| | I _{DD1} (1M) | | 4.31 | 7.11 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.55 | 5.86 | mA | |
| | I _{DD1} (10M) | | 4.50 | 7.43 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.87 | 8.04 | mA | |
| | I _{DD1} (100M) | | 6.15 | 12.30 | mA | All Input with 100Mbps, C _L =15pF |
| | I _{DD2} (100M) | | 18.89 | 37.78 | mA | |
| | NSI8261 | | | | | |
| | I _{DD1} (Q0) | | 1.67 | 2.75 | mA | All Input 0V for NSI8261x0 Or All Input at supply for NSI8261x1 |
| | I _{DD2} (Q0) | | 3.02 | 4.99 | mA | |

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|----------------|-------------------------|-----|-------|-------|------|--|
| | I _{DD1} (Q1) | | 6.62 | 10.93 | mA | All Input at supply for NSI8261x0 Or All Input 0V for NSI8261x1 |
| | I _{DD2} (Q1) | | 4.07 | 6.71 | mA | |
| | I _{DD1} (1M) | | 4.18 | 6.90 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.68 | 6.07 | mA | |
| | I _{DD1} (10M) | | 4.56 | 7.53 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.81 | 7.93 | mA | |
| | I _{DD1} (100M) | | 8.27 | 16.55 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 16.77 | 33.53 | mA | |
| NSI8262 | | | | | | |
| | I _{DD1} (Q0) | | 2.01 | 3.31 | mA | All Input 0V for NSI8261x0 Or All Input at supply for NSI8261x1 |
| | I _{DD2} (Q0) | | 2.68 | 4.43 | mA | |
| | I _{DD1} (Q1) | | 5.98 | 9.87 | mA | All Input at supply for NSI8261x0 Or All Input 0V for NSI8261x1 |
| | I _{DD2} (Q1) | | 4.71 | 7.77 | mA | |
| | I _{DD1} (1M) | | 4.06 | 6.69 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.80 | 6.28 | mA | |
| | I _{DD1} (10M) | | 4.62 | 7.63 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.75 | 7.83 | mA | |
| | I _{DD1} (100M) | | 10.40 | 20.79 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 14.64 | 29.29 | mA | |
| NSI8263 | | | | | | |
| | I _{DD1} (Q0) | | 2.35 | 3.87 | mA | All Input 0V for NSI8262x0 Or All Input at supply for NSI8262x1 |
| | I _{DD2} (Q0) | | 2.35 | 3.87 | mA | |
| | I _{DD1} (Q1) | | 5.35 | 8.82 | mA | All Input at supply for NSI8262x0 Or All Input 0V for NSI8262x1 |
| | I _{DD2} (Q1) | | 5.35 | 8.82 | mA | |
| | I _{DD1} (1M) | | 3.93 | 6.48 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.93 | 6.48 | mA | |
| | I _{DD1} (10M) | | 4.69 | 7.73 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.69 | 7.73 | mA | |
| | I _{DD1} (100M) | | 12.52 | 25.04 | mA | All Input with 100Mbps, |

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|------------|-------------------------|-----|-------|-------|------|-----------------------|
| | I _{DD2} (100M) | | 12.52 | 25.04 | mA | C _L = 15pF |

5.4. Supply Current Characteristics–2.5V Supply

(VDD1=2.5V± 10%, VDD2=2.5V± 10%, T_A=-40°C to 125°C. Unless otherwise noted, Typical values are at VDD1 = 2.5V, VDD2 = 2.5V, T_A = 25°C)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|----------------|-------------------------|-----|-------|-------|------|---|
| Supply current | NSI8260 | | | | | |
| | I _{DD1} (Q0) | | 1.29 | 2.94 | mA | All Input 0V for NSI8260x0 Or All Input at supply for NSI8260x1 |
| | I _{DD2} (Q0) | | 3.33 | 5.49 | mA | |
| | I _{DD1} (Q1) | | 7.00 | 11.55 | mA | All Input at supply for NSI8260x0 Or All Input 0V for NSI8260x1 |
| | I _{DD2} (Q1) | | 3.39 | 5.59 | mA | |
| | I _{DD1} (1M) | | 4.17 | 6.88 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.47 | 5.73 | mA | |
| | I _{DD1} (10M) | | 4.29 | 7.08 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.48 | 7.39 | mA | |
| | I _{DD1} (100M) | | 5.27 | 10.54 | mA | All Input with 100Mbps, C _L =15pF |
| | I _{DD2} (100M) | | 15.33 | 30.66 | mA | |
| | NSI8261 | | | | | |
| | I _{DD1} (Q0) | | 1.63 | 2.69 | mA | All Input 0V for NSI8261x0 Or All Input at supply for NSI8261x1 |
| | I _{DD2} (Q0) | | 2.99 | 4.93 | mA | |
| | I _{DD1} (Q1) | | 6.40 | 10.56 | mA | All Input at supply for NSI8261x0 Or All Input 0V for NSI8261x1 |
| | I _{DD2} (Q1) | | 3.99 | 6.59 | mA | |
| | I _{DD1} (1M) | | 4.05 | 6.69 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.59 | 5.92 | mA | |
| | I _{DD1} (10M) | | 4.32 | 7.13 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.45 | 7.34 | mA | |
| | I _{DD1} (100M) | | 6.95 | 13.89 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 13.65 | 27.31 | mA | |
| | NSI8262 | | | | | |

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|----------------|-------------------------|-----|-------|-------|------|---|
| | I _{DD1} (Q0) | | 1.97 | 3.25 | mA | All Input 0V for NSI8261x0 Or All Input at supply for NSI8261x1 |
| | I _{DD2} (Q0) | | 2.65 | 4.37 | mA | |
| | I _{DD1} (Q1) | | 5.80 | 9.56 | mA | All Input at supply for NSI8261x0 Or All Input 0V for NSI8261x1 |
| | I _{DD2} (Q1) | | 4.59 | 7.58 | mA | |
| | I _{DD1} (1M) | | 3.94 | 6.50 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.70 | 6.11 | mA | |
| | I _{DD1} (10M) | | 4.35 | 7.18 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.42 | 7.29 | mA | |
| | I _{DD1} (100M) | | 8.62 | 17.25 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 11.98 | 23.95 | mA | |
| NSI8263 | | | | | | |
| | I _{DD1} (Q0) | | 2.31 | 3.81 | mA | All Input 0V for NSI8262x0 Or All Input at supply for NSI8262x1 |
| | I _{DD2} (Q0) | | 2.31 | 3.81 | mA | |
| | I _{DD1} (Q1) | | 5.20 | 8.57 | mA | All Input at supply for NSI8262x0 Or All Input 0V for NSI8262x1 |
| | I _{DD2} (Q1) | | 5.20 | 8.57 | mA | |
| | I _{DD1} (1M) | | 3.82 | 6.30 | mA | All Input with 1Mbps, C _L =15pF |
| | I _{DD2} (1M) | | 3.82 | 6.30 | mA | |
| | I _{DD1} (10M) | | 4.39 | 7.24 | mA | All Input with 10Mbps, C _L =15pF |
| | I _{DD2} (10M) | | 4.39 | 7.24 | mA | |
| | I _{DD1} (100M) | | 10.30 | 20.60 | mA | All Input with 100Mbps, C _L = 15pF |
| | I _{DD2} (100M) | | 10.30 | 20.60 | mA | |

5.5. Switching Characteristics - 5V Supply

(VDD1=5V± 10%, VDD2=5V± 10%, T_A=-40°C to 125°C. Unless otherwise noted, Typical values are at **VDD1 = 5V, VDD2 = 5V, T_A = 25°C**)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|---------------------|------------------|-----|------|-----|------|---|
| Data Rate | DR | 0 | | 150 | Mbps | |
| Minimum Pulse Width | PW | | | 5.0 | ns | |
| Propagation Delay | t _{PLH} | 2.5 | 6.54 | 15 | ns | See Figure 5.11 , C _L = 15pF |

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|---|---------------|-----|------|-----|------|--|
| | t_{PHL} | 2.5 | 8.30 | 15 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Pulse Width Distortion $ t_{PHL} - t_{PLH} $ | PWD | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Rising Time | t_r | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Falling Time | t_f | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Peak Eye Diagram Jitter | $t_{JIT}(PK)$ | | 350 | | ps | |
| Channel-to-Channel Delay Skew | $t_{SK}(c2c)$ | | | 2.5 | ns | |
| Part-to-Part Delay Skew | $t_{SK}(p2p)$ | | | 5.0 | ns | |

5.6. Switching Characteristics - 3.3V Supply

($VDD1=3.3V \pm 10\%$, $VDD2=3.3V \pm 10\%$, $T_A=-40^\circ C$ to $125^\circ C$. Unless otherwise noted, Typical values are at **VDD1 = 3.3V**, **VDD2 = 3.3V**, $T_A = 25^\circ C$)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|---|---------------|-----|-----|-----|------|--|
| Data Rate | DR | 0 | | 150 | Mbps | |
| Minimum Pulse Width | PW | | | 5.0 | ns | |
| Propagation Delay | t_{PLH} | 2.5 | 7.5 | 15 | ns | See Figure 5.11 , $C_L = 15pF$ |
| | t_{PHL} | 2.5 | 8.7 | 15 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Pulse Width Distortion $ t_{PHL} - t_{PLH} $ | PWD | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Rising Time | t_r | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Falling Time | t_f | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Peak Eye Diagram Jitter | $t_{JIT}(PK)$ | | 350 | | ps | |
| Channel-to-Channel Delay Skew | $t_{SK}(c2c)$ | | | 2.5 | ns | |
| Part-to-Part Delay Skew | $t_{SK}(p2p)$ | | | 5.0 | ns | |

5.7. Switching Characteristics - 2.5V Supply

($VDD1=2.5V \pm 10\%$, $VDD2=2.5V \pm 10\%$, $T_A=-40^\circ C$ to $125^\circ C$. Unless otherwise noted, Typical values are at **VDD1 = 2.5V**, **VDD2 = 2.5V**, $T_A = 25^\circ C$)

| Parameters | Symbol | Min | Typ | Max | Unit | Comments |
|---|---------------|-----|-----|-----|------|--|
| Data Rate | DR | 0 | | 150 | Mbps | |
| Minimum Pulse Width | PW | | | 5.0 | ns | |
| Propagation Delay | t_{PLH} | 2.5 | 9.0 | 15 | ns | See Figure 5.11 , $C_L = 15pF$ |
| | t_{PHL} | 2.5 | 9.3 | 15 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Pulse Width Distortion $ t_{PHL} - t_{PLH} $ | PWD | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Rising Time | t_r | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Falling Time | t_f | | | 5.0 | ns | See Figure 5.11 , $C_L = 15pF$ |
| Peak Eye Diagram Jitter | $t_{JIT(PK)}$ | | 350 | | ps | |
| Channel-to-Channel Delay Skew | $t_{SK(c2c)}$ | | | 2.5 | ns | |
| Part-to-Part Delay Skew | $t_{SK(p2p)}$ | | | 5.0 | ns | |

5.8. Typical Performance Characteristics

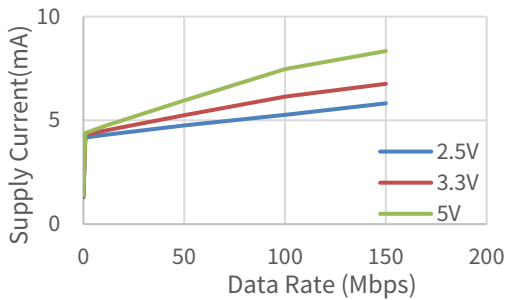


Figure 5.1 NSI8260 VDD1 Supply Current vs Data Rate

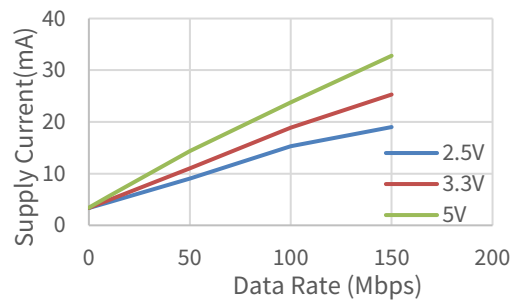


Figure 5.2 NSI8260 VDD2 Supply Current vs Data Rate

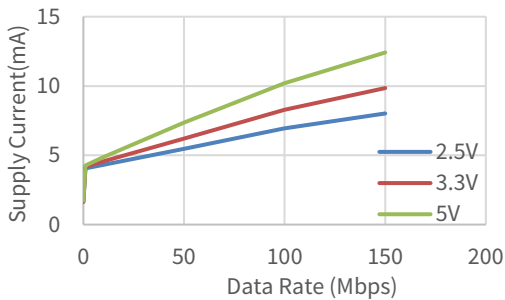


Figure 5.3 NSI8261 VDD1 Supply Current vs Data Rate

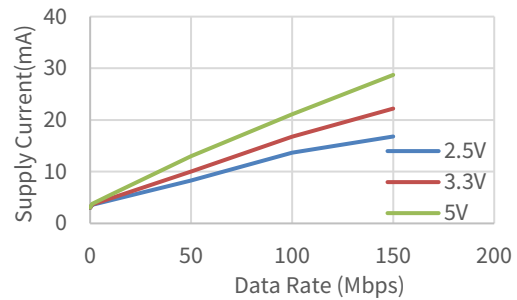


Figure 5.4 NSI8261 VDD2 Supply Current vs Data Rate

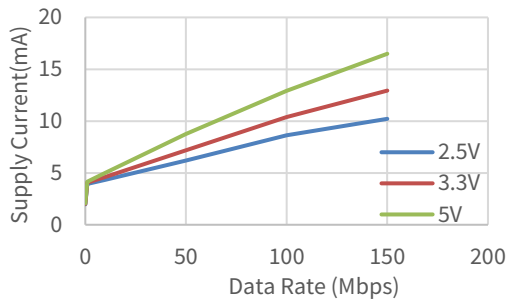


Figure 5.5 NSI8262 VDD1 Supply Current vs Data Rate

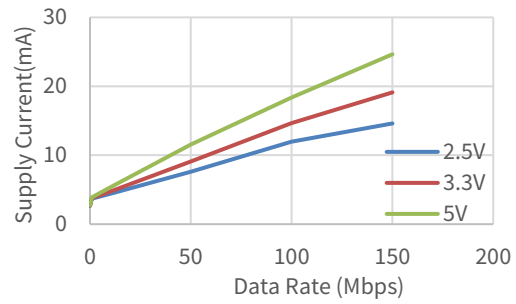


Figure 5.6 NSI8262 VDD2 Supply Current vs Data Rate

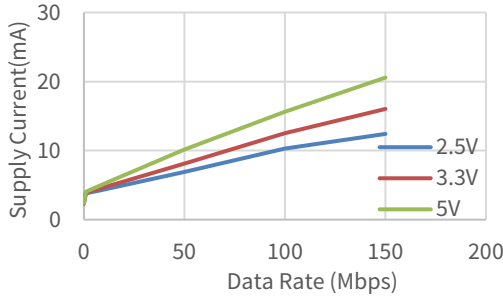


Figure 5.7 NSI8263 VDD1 Supply Current vs Data Rate

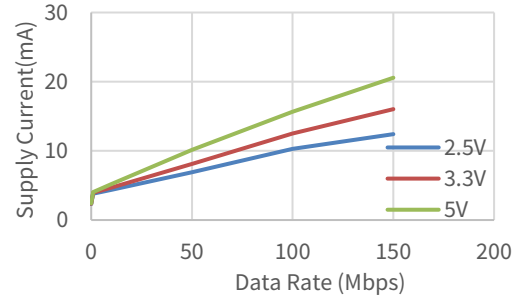


Figure 5.8 NSI8263 VDD2 Supply Current vs Data Rate

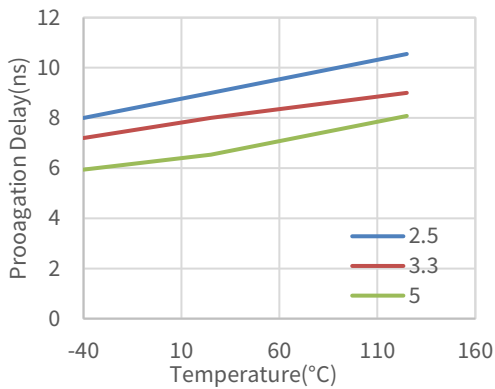


Figure 5.9 Rising Edge Propagation Delay Vs Temp

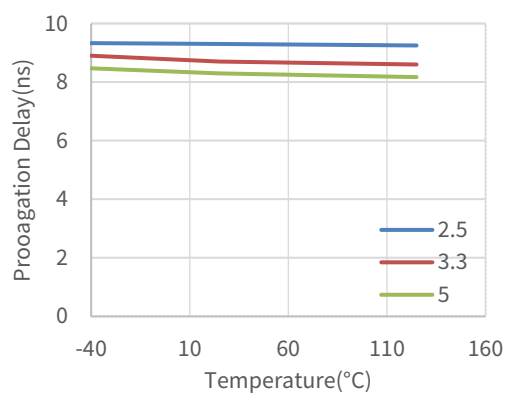
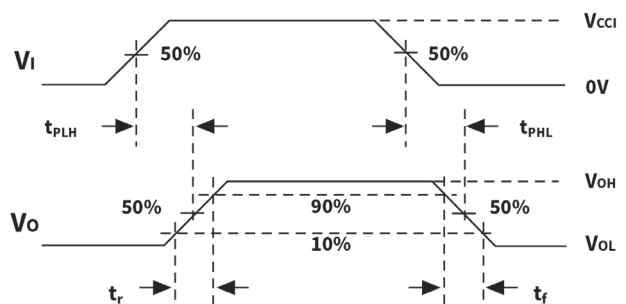
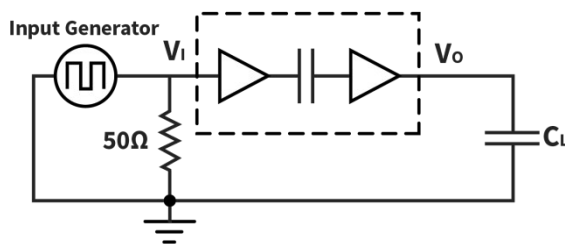


Figure 5.10 Falling Edge Propagation Delay Vs Temp

5.9. Parameter Measurement Information



(1) Input Generator Characteristics : PRR ≤ 50kHz, tr ≤ 3ns, tf ≤ 3ns, Duty cycle = 50%, Zo = 50 Ω.

Figure 5.11 Switching Characteristics Test Circuit and Waveform

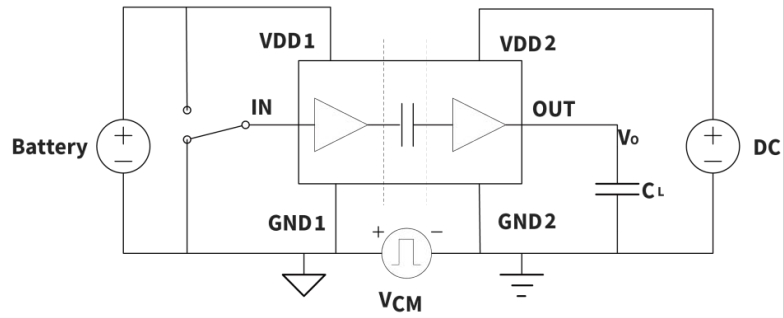


Figure 5.12 Common-Mode Transient Immunity Test Circuit

6. High Voltage Feature Description

6.1. Insulation and Safety Related Specifications

| <i>Parameters</i> | <i>Symbol</i> | <i>Value</i> | | <i>Comments</i> |
|--|---------------|-------------------|-------------|---------------------------------------|
| | | SOP16 (300mil) | <i>Unit</i> | |
| Minimum External Clearance | CLR | 8 | mm | IEC 60664-1:2007 |
| Minimum External Creepage | CPG | 8 | mm | IEC 60664-1:2007 |
| Distance Through Insulation | DTI | 28 | µm | Distance through insulation |
| Tracking Resistance (Comparative Tracking Index) | CTI | >600 | V | DIN EN 60112 (VDE 0303-11); IEC 60112 |
| Material Group | | I | | IEC 60664-1 |

| <i>Description</i> | <i>Test Condition</i> | <i>Value</i> |
|-------------------------------------|------------------------------------|-------------------|
| | | SOP16 (300mil) |
| Overvoltage Category per IEC60664-1 | For Rated Mains Voltage ≤ 150Vrms | I to IV |
| | For Rated Mains Voltage ≤ 300Vrms | I to IV |
| | For Rated Mains Voltage ≤ 600Vrms | I to IV |
| | For Rated Mains Voltage ≤ 1000Vrms | I to III |
| Climatic Classification | | 40/125/21 |
| Pollution Degree per DIN VDE 0110 | | 2 |

6.2. Insulation Characteristics

| <i>Description</i> | <i>Test Condition</i> | <i>Symbol</i> | <i>Value</i> | |
|--------------------------------------|-----------------------|-------------------|-------------------|-------------------|
| | | | SOP16 (300mil) | <i>Unit</i> |
| Maximum repetitive isolation voltage | | V _{IORM} | 2121 | V _{PEAK} |
| Maximum working isolation voltage | AC Voltage | V _{IOWM} | 1500 | V _{RMS} |
| | DC Voltage | | 2121 | V _{DC} |

| Description | Test Condition | Symbol | Value | |
|-------------------------------------|--|-------------------|-------------------|-------------------|
| | | | SOP16 (300mil) | Unit |
| Apparent Charge | Method a, after Input/output safety test subgroup 2/3, $V_{ini}=V_{IOTM}$, $t_{ini} = 60 \text{ s}$, $V_{pd(m)}=1.2*V_{IORM}$, $t_m=10\text{s}$. | q _{pd} | <5 | pC |
| | Method a, after environmental tests subgroup 1, $V_{ini}=V_{IOTM}$, $t_{ini}=60\text{s}$, $V_{pd(m)}=1.6*V_{IORM}$, $t_m=10\text{s}$ | | | pC |
| | Method b, routine test (100% production) and preconditioning (type test); $V_{ini}=1.2*V_{IOTM}$, $t_{ini}=1\text{s}$ $V_{pd(m)}=1.875*V_{IORM}$, $t_m=1\text{s}$ (method b1) or $V_{pd(m)}=V_{ini}$, $t_m=t_{ini}$ (method b2) | | | pC |
| Maximum transient isolation voltage | t = 60 sec | V _{IOTM} | 8000 | V _{PEAK} |
| Maximum impulse voltage | Tested in air, 1.2/50-us waveform per IEC62368-1 | V _{IMP} | 6250 | V _{PEAK} |
| Maximum Surge Isolation Voltage | Test method per IEC62368-1, 1.2/50us waveform, $V_{IOSM} \geq V_{IMP} \times 1.3$ | V _{IOSM} | 10000 | V _{PEAK} |
| Isolation resistance | $V_{IO} = 500\text{V}$, $T_{amb}=25^\circ\text{C}$ | R _{IO} | >10 ¹² | Ω |
| | $V_{IO} = 500\text{V}$, $100^\circ\text{C} \leq T_{amb} \leq 125^\circ\text{C}$ | R _{IO} | >10 ¹¹ | Ω |
| | $V_{IO} = 500\text{V}$, $T_{amb}=T_s$ | R _{IO} | >10 ⁹ | Ω |
| Isolation capacitance | f = 1MHz | C _{IO} | 0.8 | pF |
| UL1577 | | | | |
| Insulation voltage per UL | $V_{TEST} = V_{ISO}$, t = 60 s (qualification), $V_{TEST} = 1.2 \times V_{ISO}$, t = 1 s (100% production test) | V _{ISO} | 5000 | V _{RMS} |

6.3. Safety-Limiting Values

Reinforced isolation safety-limiting values as outlined in VDE 0884-17 of NSI826xC-DSWR

| Description | Test Condition | Value | Unit |
|----------------------------------|--|-------|------------------|
| Safety Supply Power | $R_{\theta JA} = 60.3 \text{ }^\circ\text{C/W}$, $T_J = 150 \text{ }^\circ\text{C}$, $T_A = 25 \text{ }^\circ\text{C}$ | 2073 | mW |
| Safety Supply Current | $R_{\theta JA} = 60.3 \text{ }^\circ\text{C/W}$, $V_I = 5\text{V}$, $T_J = 150 \text{ }^\circ\text{C}$, $T_A = 25 \text{ }^\circ\text{C}$ | 414 | mA |
| Safety Temperature ²⁾ | | 150 | $^\circ\text{C}$ |

- 1) Calculate with the junction-to-air thermal resistance, $R_{\theta JA}$, of SOP16(300mil) package ([Thermal Information Table](#)) which is that of a device installed on a low effective thermal conductivity test board (1s) according to JESD51-3.
- 2) The maximum safety temperature has the same value as the maximum junction temperature (T_J) specified for the device.

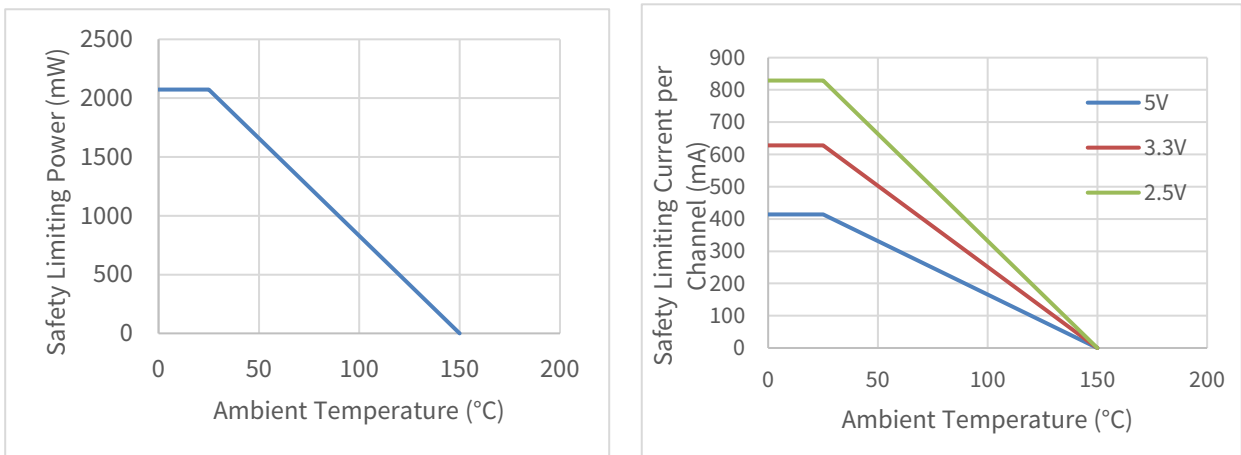


Figure 6.1 NSI826xC-DSWR Thermal Derating Curve, Dependence of Safety Limiting Values with Case Temperature per DIN EN IEC 60747-17 (VDE 0884-17)

6.4. Regulatory Information

The NSI826xC-DSWR are approved or pending approval by the organizations listed in table.

| CUL | VDE | CQC | TUV | |
|---|---|---|--------------------------------------|---------------------------------------|
| UL 1577 Component Recognition Program | Approved under CSA Component Acceptance Notice 5A | DIN EN IEC 60747-17 (VDE 0884-17) | Certified according to GB4943.1-2022 | Certified According to EN IEC 62368-1 |
| Single Protection, 5000V _{rms} Isolation voltage | Single Protection, 5000V _{rms} Isolation voltage | Reinforced Insulation $V_{IORM}=2121\text{Vpeak}$ $V_{IOTM}=8000\text{Vpeak}$ $V_{IOSM}=10000\text{Vpeak}$ | Reinforced insulation | 5000Vrms for 1min |
| E500602 | E500602 | File (40052820) | CQC20001264939 | R50574061 |

7. Function Description

7.1. Overview

The NSI826xC is a Six-channel digital isolator based on a capacitive isolation barrier technique. The digital signal is modulated with RF carrier generated by the internal oscillator at the Transmitter side. Then it is transferred through the capacitive isolation barrier and demodulated at the Receiver side.

The NSI826xC devices are high reliability six-channel digital isolator. The NSI826xC device is safety certified by UL1577 support 5kV_{rms} insulation withstand voltages, while providing high electromagnetic immunity and low emissions at low power consumption. The data rate of the NSI826xC is up to 150Mbps, and the common-mode transient immunity (CMTI) is up to 250kV/us. The NSI826xC device provides digital channel direction configuration and the default output level configuration when the input power is lost. Wide supply voltage of the NSI826xC device support to connect with most digital interface directly, easy to do the level shift. High system level EMC performance enhance reliability and stability of use.

The NSI826xC has a default output status when VDDIN is unready and VDDOUT is ready as shown in Table 7.1, which helps for diagnosis when power is missing at the transmitter side. The output B follows the same status with the input A after powering up.

Table 7.1 Output status vs. power status

| <i>Input¹</i> | <i>VDDIN status</i> | <i>VDDOUT status</i> | <i>Output</i> | <i>Comment</i> |
|---|---------------------|----------------------|------------------------------|--|
| H | Ready | Ready | H | Normal operation. |
| L | Ready | Ready | L | |
| X | Unready | Ready | L(NSI826xC0) H(NSI826xC1) | The output follows the same status with the input after input side VDD is powered on. |
| X | Ready | Unready | Undetermined | The output follows the same status with the input after output side VDD is powered on. |
| Note: H=Logic high; L=Logic low; X=Logic low or logic high VDDIN is input side power; VDDOUT is output side power. (1) There is a protection diode between the input and the VDDIN. When the VDDIN is floating, the strong drive signal through the input pin will put the VDDIN in an indeterminate state. | | | | |

7.2. OOK Modulation

NSI8266 is based on a capacitive isolation barrier technique and the digital signal is modulated with RF carrier generated by the internal oscillator at the transmitter side, as shown in Figure 7.1 to Figure 7.2, then it is transferred through the capacitive isolation barrier and demodulated at the receiver side. The modulation uses OOK modulation technique with key benefits of high noise immunity and low radiation EMI.

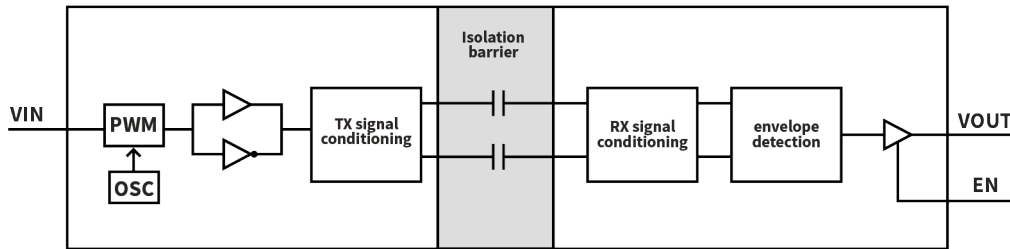


Figure 7.1 Single Channel Function Block Diagram

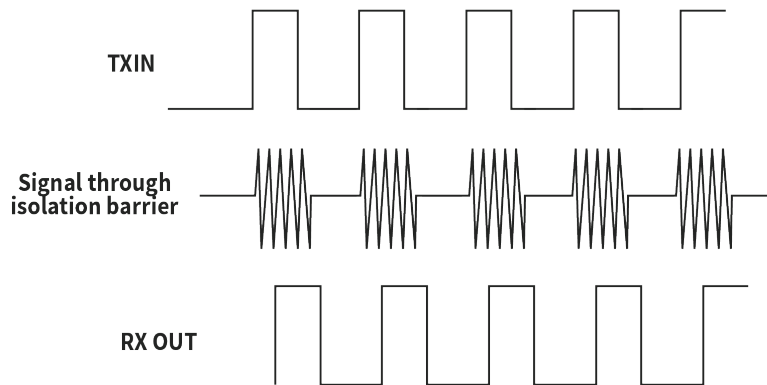


Figure 7.2 OOK Modulation

8. Application Note

8.1. Typical Application Circuit

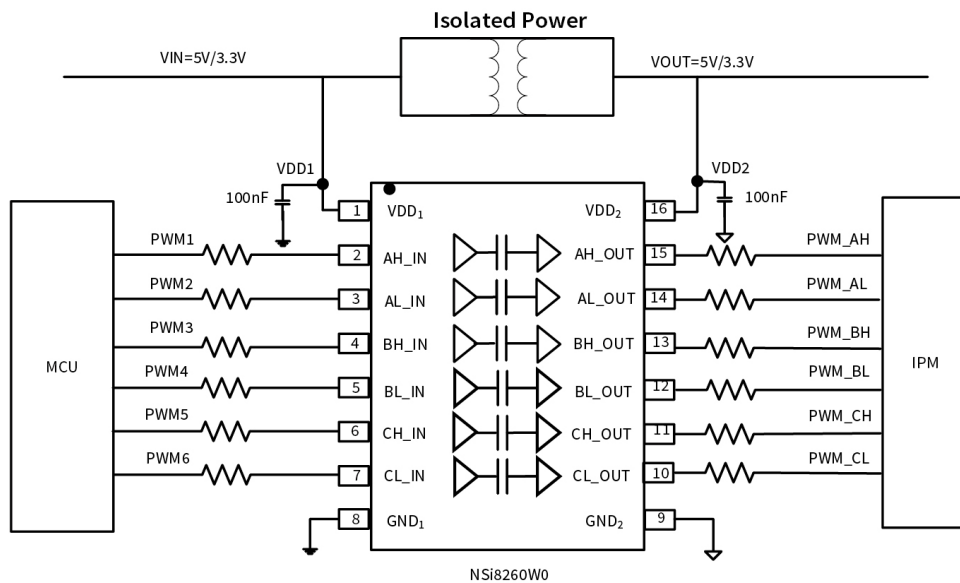


Figure 8.1 Typical PWM isolation circuit for IPM

8.2. PCB Layout

The NSI826xC requires a 0.1 μF bypass capacitor between VDD1 and GND1, VDD2 and GND2. The capacitor should be placed as close as possible to the package. Figure 8.2 to Figure 8.3 show the recommended PCB layout, make sure the space under the chip should keep free from planes, traces, pads and via. To enhance the robustness of a design, the user may also include resistors (50–300 Ω) in series with the inputs and outputs if the system is excessively noisy. The series resistors also improve the system reliability such as latch-up immunity.

The typical output impedance of an isolator driver channel is approximately 50 Ω , $\pm 40\%$. When driving loads where transmission line effects will be a factor, output pins should be appropriately terminated with controlled impedance PCB traces.

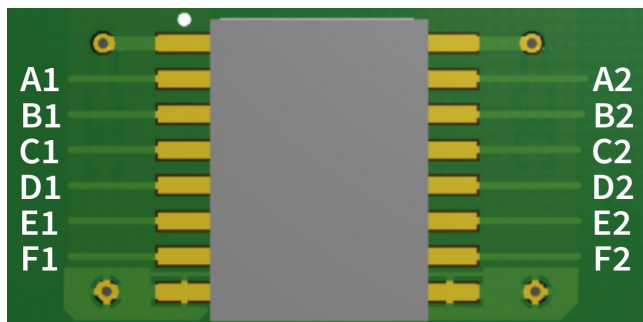


Figure 8.2 Recommended PCB Layout — Top Layer



Figure 8.3 Recommended PCB Layout — Bottom Layer

8.3. High Speed Performance

Figure 8.4 shows the eye diagram of NSI826xC at 50Mbps data rate output. The result shows a typical measurement on NSI826xC with low jitter and wide open eye characteristics.

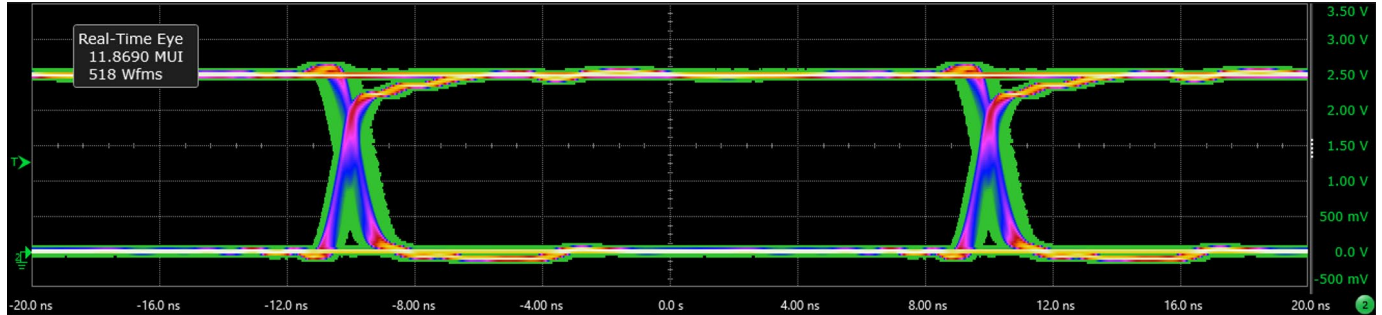


Figure 8.4 Eye Diagram at 50Mbps PRBS 2¹⁶-1, 2.5V and 25°C

8.4. Typical Supply Current Equations

The typical supply current of NSI826xC can be calculated using below equations. I_{DD1} and I_{DD2} are typical supply currents measured in mA, f is data rate measured in Mbps, C_L is the capacitive load measured in pF

NSI8260:

$$I_{DD1} = 0.19 * a1 + 1.45 * b1 + 0.82 * c1.$$

$$I_{DD2} = 1.36 + VDD2 * f * C_L * c1 * 10^{-9}$$

When a1 is the channel number of default state input at side 1, b1 is the channel number of non-default state input at side 1, c1 is the channel number of switch signal input at side 1.

NSI8261:

$$I_{DD1} = 0.87 + 1.26 * b1 + 0.63 * c1 + VDD1 * f * C_L * c2 * 10^{-9}$$

$$I_{DD2} = 0.87 + 1.26 * b2 + 0.63 * c2 + VDD2 * f * C_L * c1 * 10^{-9}$$

When b1 is the channel number of non-default state input at side 1, c1 is the channel number of switch signal input at side 1, b2 is the channel number of non-default state input at side 2, c2 is the channel number of switch signal input at side 2.

NSI8262:

$$I_{DD1} = 0.87 + 1.26 * b1 + 0.63 * c1 + VDD1 * f * C_L * c2 * 10^{-9}$$

$$I_{DD2} = 0.87 + 1.26 * b2 + 0.63 * c2 + VDD2 * f * C_L * c1 * 10^{-9}$$

When b1 is the channel number of non-default state input at side 1, c1 is the channel number of switch signal input at side 1, b2 is the channel number of non-default state input at side 2, c2 is the channel number of switch signal input at side 2.

NSI8263:

$$I_{DD1} = 0.87 + 1.26 * b1 + 0.63 * c1 + VDD1 * f * C_L * c2 * 10^{-9}$$

$$I_{DD2} = 0.87 + 1.26 * b2 + 0.63 * c2 + VDD2 * f * C_L * c1 * 10^{-9}$$

When b1 is the channel number of non-default state input at side 1, c1 is the channel number of switch signal input at side 1, b2 is the channel number of non-default state input at side 2, c2 is the channel number of switch signal input at side 2.

9. Package Information

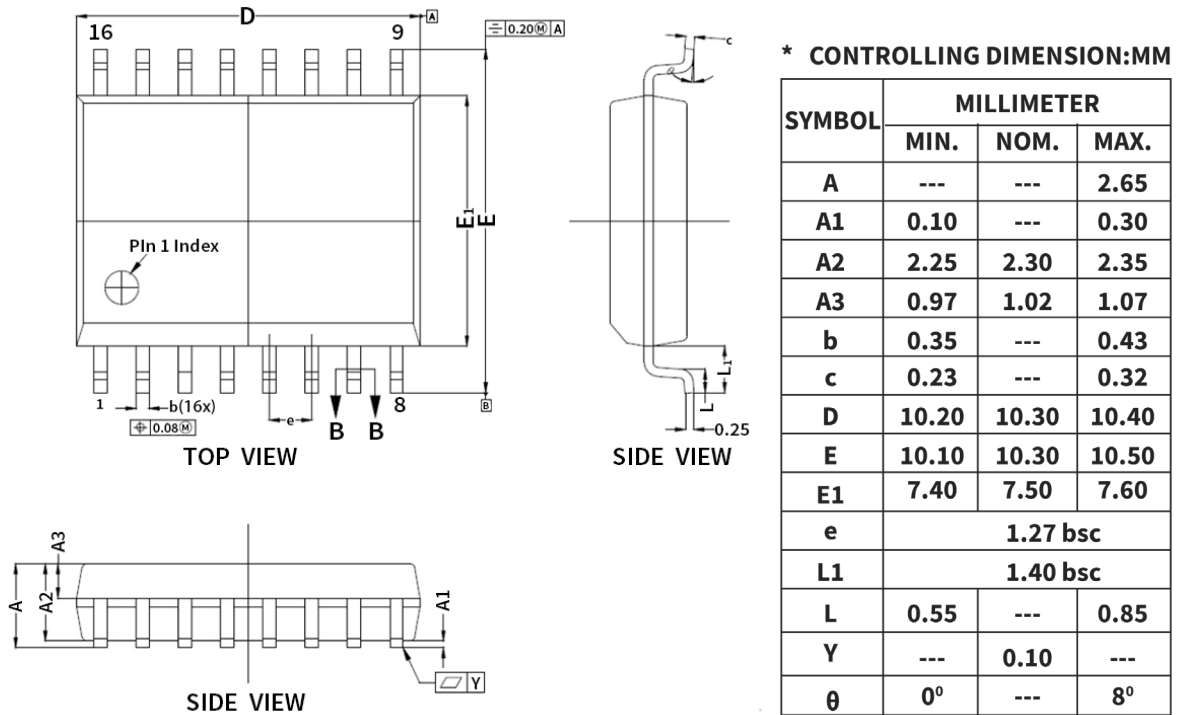


Figure 9.1 SOP16(300mil) Package Shape and Dimension in millimeters

NOTE: This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.

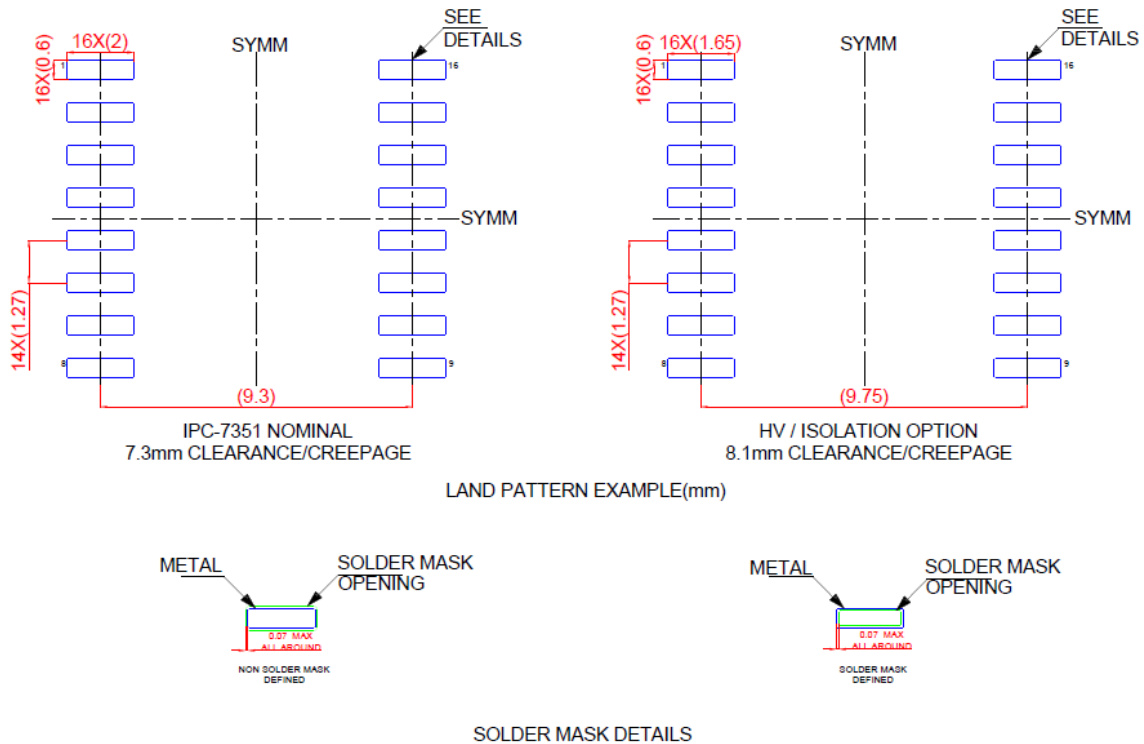


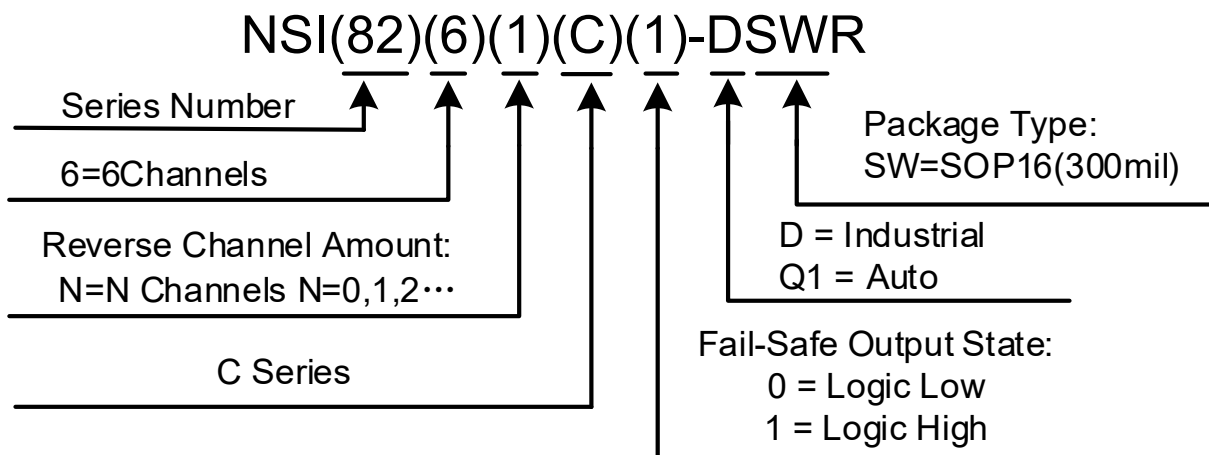
Figure 9.2 SOP16(300mil) Package Board Layout Example

10. Order Information

| Part Number | Isolation Rating (kV) | Number of side 1 inputs | Number of side 2 inputs | Max Data Rate (Mbps) | Default Output State | Temperature | MSL | Package Type | Package Drawing | SPQ |
|-----------------|-----------------------|-------------------------|-------------------------|----------------------|----------------------|--------------|-----|----------------|-----------------|------|
| NSI8260C 0-DSWR | 5 | 6 | 0 | 150 | Low | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |
| NSI8260C 1-DSWR | 5 | 6 | 0 | 150 | High | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |
| NSI8261C 0-DSWR | 5 | 5 | 1 | 150 | Low | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |
| NSI8261C 1-DSWR | 5 | 5 | 1 | 150 | High | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |
| NSI8262C 0-DSWR | 5 | 4 | 2 | 150 | Low | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |
| NSI8262C 1-DSWR | 5 | 4 | 2 | 150 | High | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |
| NSI8263C 0-DSWR | 5 | 3 | 3 | 150 | Low | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |
| NSI8263C 1-DSWR | 5 | 3 | 3 | 150 | High | -40 to 125°C | 3 | SOP16 (300mil) | SOW16 | 1000 |

NOTE: All packages are RoHS-compliant with peak reflow temperatures of 260 °C according to the JEDEC industry standard classifications and peak solder temperatures.

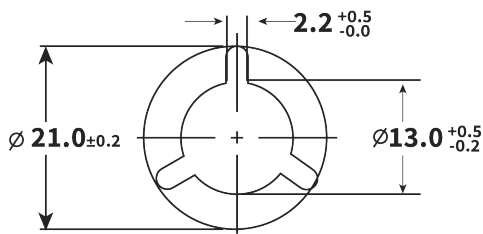
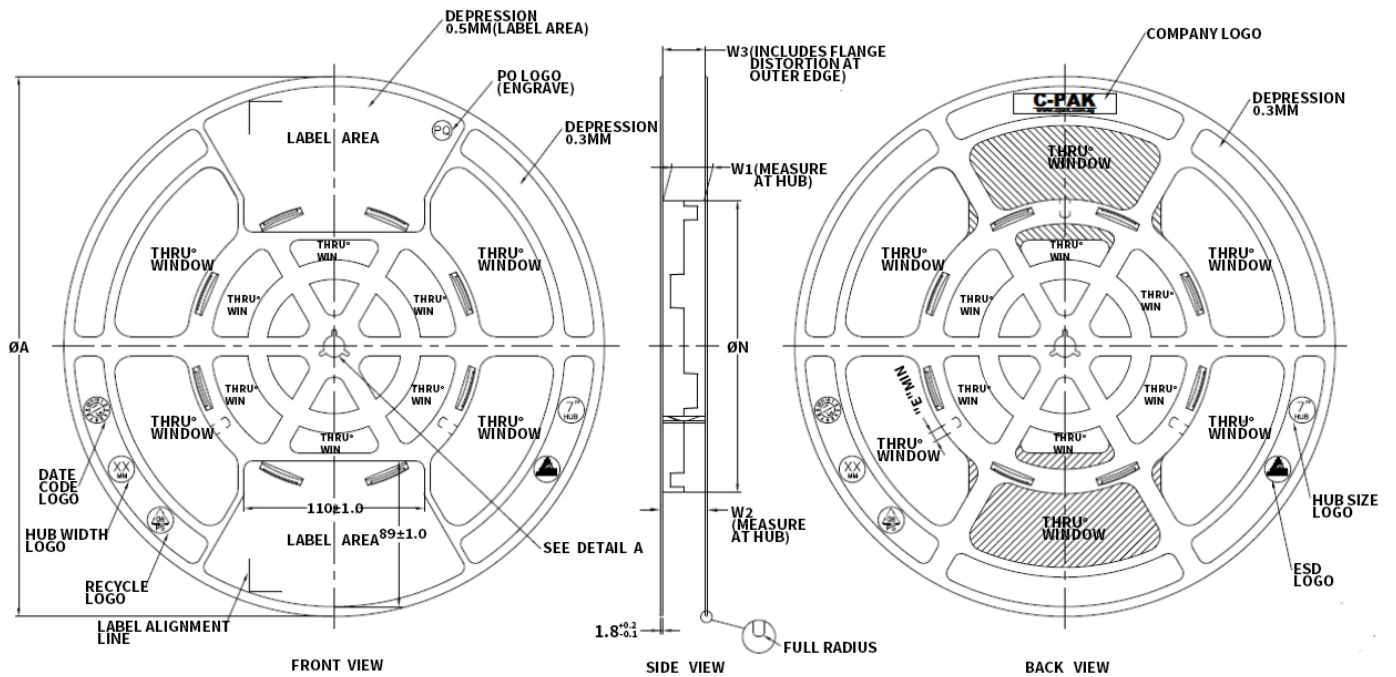
Part Number Rule:



11. Documentation Support

| Part Number | Product Folder | Datasheet | Technical Documents | Isolator selection guide |
|-------------|----------------|-----------|---------------------|--------------------------|
| NSI826xC | tbd | tbd | tbd | tbd |

12. Tape and Reel Information

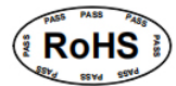
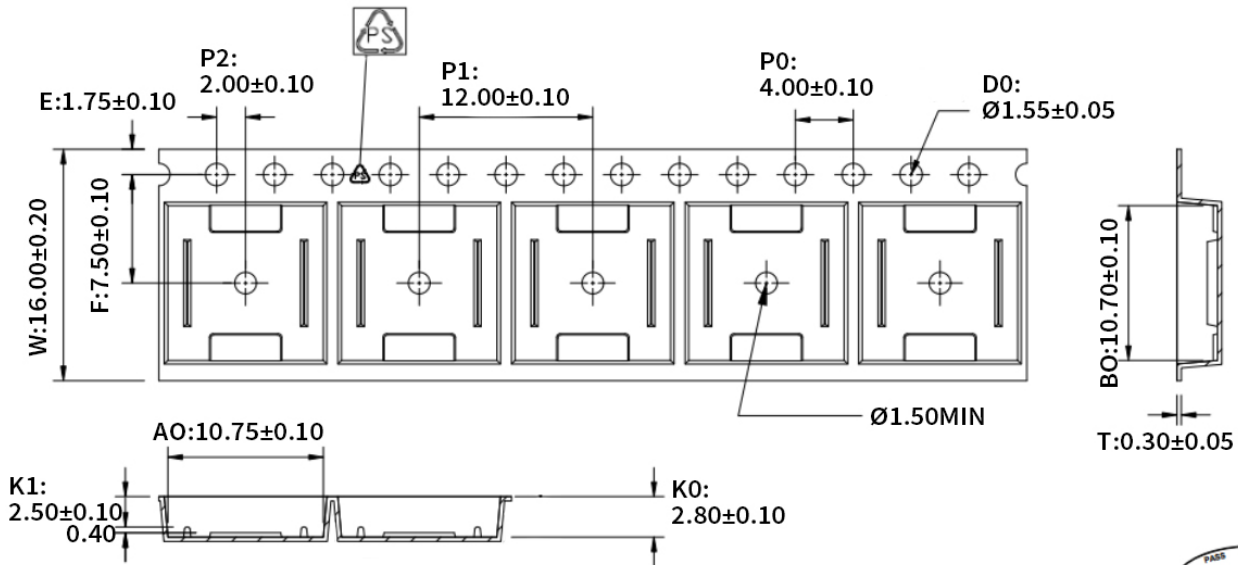


**ARBOR HOLE
DETAIL A
SCALE: 3:1**

| PRODUCT SPECIFICATION | | | | | | |
|-----------------------|----------|----------|--------------------------------------|----------|---|---------|
| TAPE WIDTH | Ø A ±2.0 | Ø N ±2.0 | W1 | W2 (Max) | W3 | E (MIN) |
| 08MM | 330 | 178 | 8.4 ^{+1.5} _{-0.0} | 14.4 | SHALL ACCOMMODATE TAPE WIDTH WITHOUT INTERFERENCE | 5.5 |
| 12MM | 330 | 178 | 12.4 ^{+2.0} _{-0.0} | 18.4 | | 5.5 |
| 16MM | 330 | 178 | 16.4 ^{+2.0} _{-0.0} | 22.4 | | 5.5 |
| 24MM | 330 | 178 | 24.4 ^{+2.0} _{-0.0} | 30.4 | | 5.5 |
| 32MM | 330 | 178 | 32.4 ^{+2.0} _{-0.0} | 38.4 | | 5.5 |

| SURFACE RESISTIVITY | | | |
|---------------------|---|---------------------|------------|
| LEGEND | SR RANGE | TYPE | COLOUR |
| A | BELOW 10 ¹² | ANTISTATIC | ALL TYPES |
| B | 10 ⁶ TO 10 ¹¹ | STATIC DISSIPATIVE | BLACK ONLY |
| C | 10 ⁵ & BELOW 10 ⁵ | CONDUCTIVE(GENERIC) | BLACK ONLY |
| E | 10 ⁹ TO 10 ¹¹ | ANTISTATIC(COATED) | ALL TYPES |

Figure 12.1 Reel Information (for all packages)



1. 10 sprocket hole pitch cumulative tolerance ± 0.20 .
2. Carrier camber is within 1 mm in 250 mm.
3. Material : Black Conductive Polystyrene Alloy.
4. All dimensions meet EIA-481 requirements.
5. Thickness: 0.30 ± 0.05 mm.
6. Packing length per 22" reel: 378 Meters. (Rewind N=122)
7. Component load per 13" reel: 1000 pcs.
8. Surface resistivity: $10^5 \sim 10^{10} \Omega/\square$

| | |
|----|------------|
| W | 16.00±0.20 |
| A0 | 10.75±0.10 |
| B0 | 10.70±0.10 |
| K0 | 2.80±0.10 |
| K1 | 2.50±0.10 |

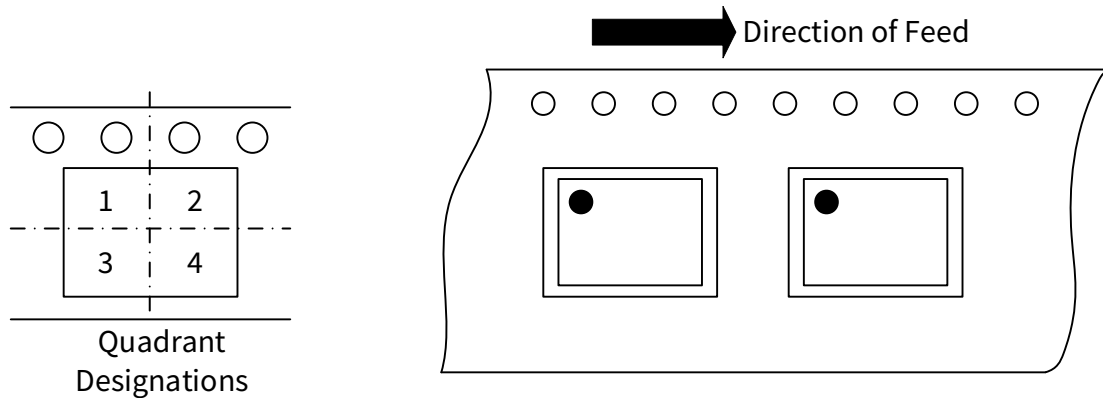


Figure 12.2 Tape Information of SOP16(300mil)

13. Revision history

| Revision | Description | Date |
|-----------------|---|-------------|
| 1.0 | Initial version | 2022/5/10 |
| 1.1 | Delate "Isolation barrier life: >60 years". Change DTI from 32 to 28, Change Min Storage Temperature to -65, add Junction Temperature, delate AEC-Q100 information. | 2022/9/7 |
| 1.2 | Update Regulatory Information and Safety Regulatory Approvals. Correct Typical Supply Current Equations, the icon in section 8 and MSL. Change the typical CMTI from 150 to 250 kV/us, change the minimum CMTI from 100 to 200 kV/us, change the maximum Data rate from 100 to 150Mbps. | 2023/5/30 |
| 1.3 | Correct formatting and images. Update Input characteristics. Update Safety certification info throughout the document. Update eye diagram. Update Package Information. Update Function Description. | 2025/1/13 |

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